	Roll No
Total No. of Questions : 8]	[Total No. of Printed Pages : 2

## **EE/EX-3004-CBGS**

## **B.E. III Semester**

Examination, June 2020

## Choice Based Grading System (CBGS) Analog Electronics

Time: Three Hours

Maximum Marks: 70

*Note:* i) Attempt any five questions out of eight questions.

- ii) All questions carry equal marks.
- iii) Assume suitable data, if required.
- 1. a) Write some of the difference between p-n junction and p-n junction diode? Explain with a suitable example.
  - b) Explain the temperature dependence and break down characteristics of p-n junction diode.
- 2. a) Discuss the comparison between varacter diode, Schottky diode and Tunnel Diode.
  - b) What do you mean by Transistors? Give a brief crassification of all types of transistors.
- 3. a) Explain the comparison between CB, CE and CC configuration.
  - b) Derive a relation for drain current Id for E MOSFET.
- 4. a) Explain the concept of feedback in any circuit? Explain it with example.
  - b) Define and explain the Barkhausen Criterion. Explain the concept of frequency oscillations.

EE/EX-3004-CBGS

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- 5. a) Discuss about the current series and current shunt feedback with suitable circuit.
  - b) Write any five differences between the push pull and complementary push pull amplifiers.
- 6. a) Write short note on De rating curve. Explain the class AB amplifier. Derive its relation as well.
  - b) Write short note on Hartley colpitts oscillator and UJT Oscillator circuits.
- 7. a) Derive expressions for the multi vibrators and square wave generators for the circuits which behave as an OPAMPS.
  - b) Derive an expression for the Op-Amp inverting and non-inverting circuits.
- 8. Write short notes on any four of the following:
  - a) Schmitt Trigger
  - b) Wein Bridge Oscillator
  - c) LED
  - d) FET
  - e) Cascade amplifier
  - f) Boot strapping technique

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EE/EX-3004-CBGS